

no 45
410 0

General Description

FNB41060 is a Motion SPM45 module providing a fully-featured, high-performance inverter output stage for AC Induction, BLDC, and PMSM motors. These modules integrate optimized gate drive of the built-in IGBTs to minimize EMI and losses, while also providing multiple on-module protection features including under-voltage lockouts, over-current shutdown, thermal monitoring, and fault reporting. The built-in, high-speed HVIC requires only a single supply voltage and translates the incoming logic-level gate inputs to the high-voltage, high-current drive signals required to properly drive the module's robust short-circuit-rated IGBTs. Separate negative IGBT terminals are available for each phase to support the widest variety of control algorithms.

Features

- UL Certified No. E209204 (UL1557)
- 600 V – 10 A 3-Phase IGBT Inverter with Integral Gate Drivers and Protection
- Low Thermal Resistance Using Ceramic Substrate
- Low-Loss, Short-Circuit Rated IGBTs
- Built-In Bootstrap Diodes and Dedicated Vs Pins Simplify PCB Layout
- Built-In NTC Thermistor for Temperature Monitoring
- Separate Open-Emitter Pins from Low-Side IGBTs for Three-Phase Current Sensing
- Single-Grounded Power Supply
- Isolation Rating: 2000 V_{rms} / Min.
- This Device is Pb-Free and Halide Free

Applications

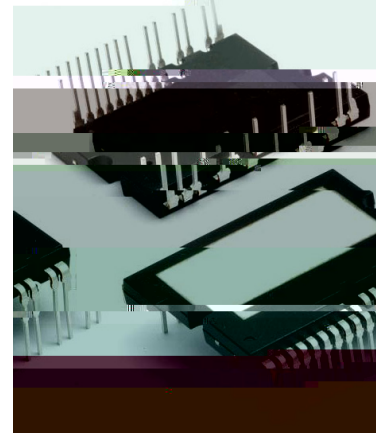
- Motion Control – Home Appliance / Industrial Motor

Integrated Power Functions

- 600 V – 10 A IGBT Inverter for Three-phase DC / AC Power Conversion (Please Refer to Figure 2)

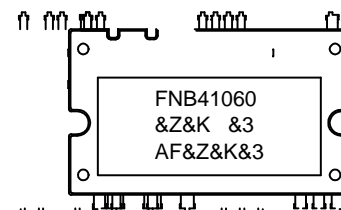
Integrated Drive, Protection, and System Control Functions

- For Inverter High-side IGBTs: Gate Drive Circuit, High-voltage Isolated High-speed Level Shifting Control Circuit Under-Voltage Lock-Out (UVLO) Protection
- For Inverter Low-side IGBTs: Gate Drive Circuit, Short-Circuit Protection (SCP) Control Supply Circuit Under-Voltage Lock-Out (UVLO) Protection
- Fault Signaling: Corresponding to UVLO (Low-side Supply) and SC Faults
- Input Interface: Active-HIGH Interface, Works with 3.3 / 5 V Logic, Schmitt Trigger Input



SPMAA-A26 / 26LD, PDD STD, CERAMIC TYPE,
STANDARD DUAL FORM
CASE MODFA

MARKING DIAGRAM



- FNB41060 = Specific Device Code
- &Z = Assembly Plant Code
- &K = 2-Digits Lot Run Traceability Code
- &3 = 3-Digit Date Code
- AF = Specific Product Name

ORDERING INFORMATION

Device	Package	Shipping
FNB41060	SPMAA-A26 (Pb-Free, Halide Free)	12 Units / Rail

Related Resources

- [AN-9070](#) – Motion SPM 45 Series Users Guide
- [AN-9071](#) – Motion SPM 45 Series Thermal Performance Information
- [AN-9072](#) – Motion SPM 45 Series Mounting Guidance
- RD-344 – Reference Design (Three Shunt Solution)
- RD-345 – Reference Design (One Shunt Solution)

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PIN CONFIGURATION

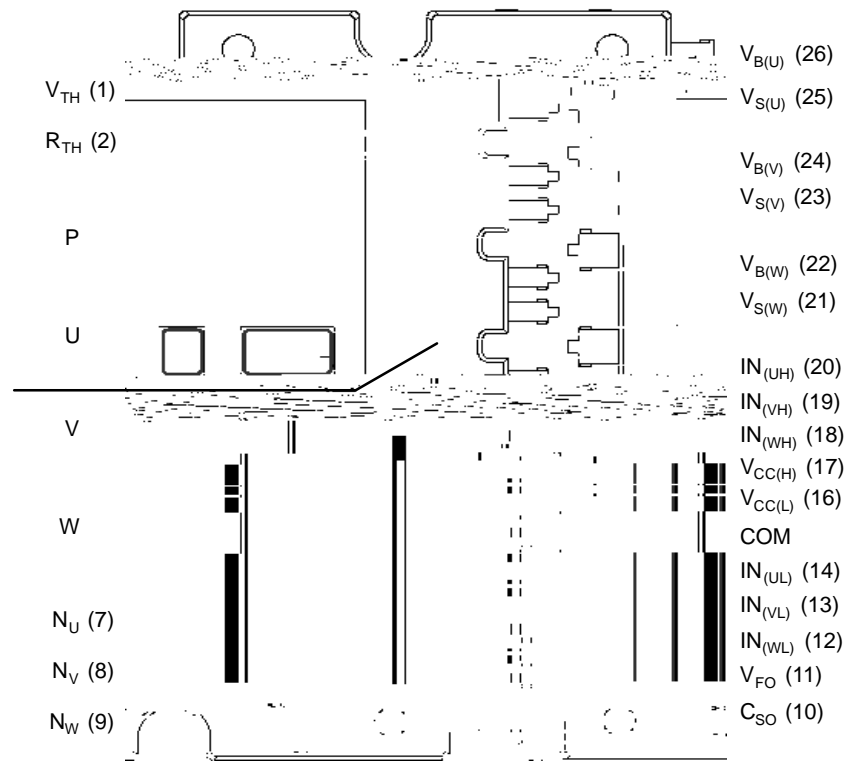


Figure 1. Top View

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ABSOLUTE MAXIMUM RATINGS (T_J = 25°C unless otherwise specified)

Symbol	Parameter	Conditions	Rating	Unit
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INVERTER PART

V _{PN}	Supply Voltage	Applied between P – N _U , N _V , N _W	450	V
V _{PN(Surge)}	Supply Voltage (Surge)	Applied between P – N _U , N _V , N _W	500	V
V _{CES}	Collector–Emitter Voltage		600	V
I _{O,25}	Output Phase Current	T _C = 25°C, T _J < 150°C (Note 4)	10	A
I _{O,100}	Output Phase Current	T _C = 100°C, T _J < 150°C (Note 4)	5	A
I _{pk}	Output Peak Phase Current	T _C = 25°C, T _J < 150°C, Under 1 ms Pulse Width	15	A
P _C	Collector Dissipation	T _C = 25°C per Chip	32	W
T _J	Operating Junction Temperature	(Note 5)	– 40~150	°C

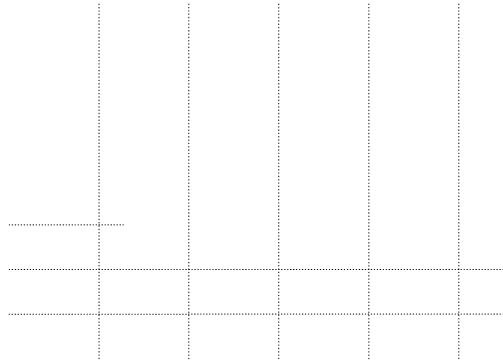
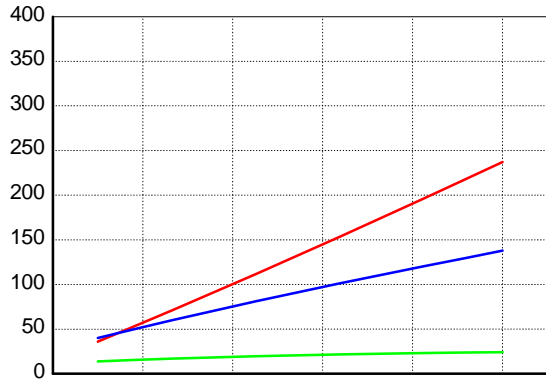
CONTROL PART

V _{CC}	Control Supply Voltage	Applied between V _{CC(H)} , V _{CC(L)} – COM	20	V
V _{BS}	High–Side Control Bias Voltage	Applied between V _{B(U)} – V _{S(U)} , V _{B(V)} – V _{S(V)} , V _{B(W)} – V _{S(W)}	20	V
V _{IN}	Input Signal Voltage	Applied between IN _(UH) , IN _(VH) , IN _(WH) , IN _(UL) , IN _(VL) , IN _(WL) – COM	–0.3~V _{CC} + 0.3	V
V _{FO}	Fault Output Supply Voltage	Applied between V _{FO} – COM	–0.3~V _{CC} + 0.3	V
I _{FO}	Fault Output Current	Sink Current at V _{FO} pin	1	mA
V _{SC}	Current–Sensing Input Voltage	Applied between C _{SC} – COM	–0.3~V _{CC} + 0.3	V

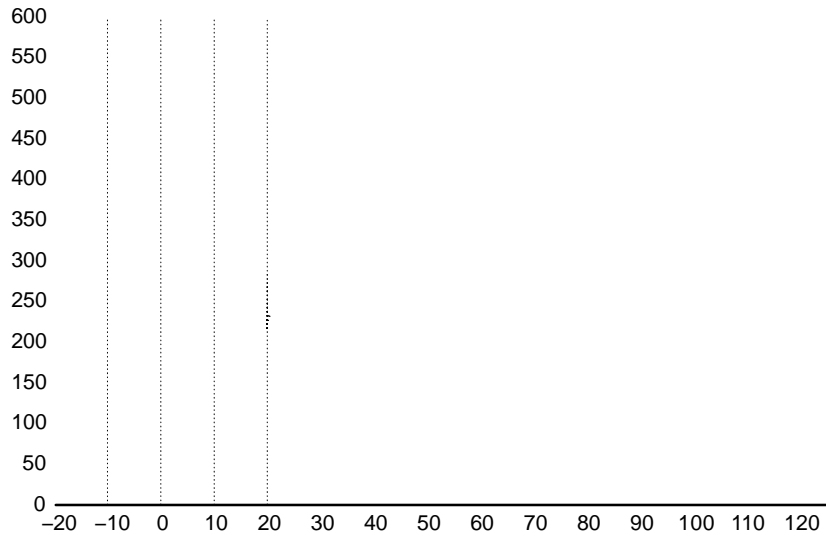
BOOTSTRAP DIODE PART

V _{RRM}	Maximum Repetitive Reverse Voltage		600	V
I _F	Forward Current	T _C = 25°C, T _J < 150°C	0.50	A
I _{FP}	Forward Current (Peak)			

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MECHANICAL CHARACTERISTICS AND RATINGS

Parameter	Conditions	Min	Typ	Max	Unit
Device Flatness	See Figure 8	0	-	+120	μm
Mounting Torque	Mounting Screw: M3 See Figure 9	0.6	0.7	0.8	$\text{N} \cdot \text{m}$

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NOTES:

16. To avoid malfunction, the wiring of each input should be as short as possible (less than 2–3 cm).
17. By virtue of integrating an application-specific type of HVIC inside the Motion SPM 45 product, direct coupling to MCU terminals without any optocoupler or transformer isolation is possible.
18. V_{FO} output is open-drain type. This signal line should be pulled up to the positive side of the MCU or control power supply with a resistor that makes I_{FO} up to 1 mA (please refer to Figure 13).
19. C_{SP15} of around seven times larger than bootstrap capacitor C_{BS} is recommended.
20. Input signal is active-HIGH type. There is a 5 k Ω resistor inside the IC to pull down each input signal line to GND. RC coupling circuits is recommended for the prevention of input signal oscillation. $R_S C_{PS}$ time constant should be selected in the range 50~ 50 ns (recommended $R_S = 100 \Omega$, $C_{PS} = 1 \text{ nF}$).

Figure 14. Typical Application Circuit

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